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Organic salt mediated growth of phase pure and stable all-inorganic CsPbX₃ (X = I, Br) perovskites for efficient photovoltaics

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ABSTRACT

All-inorganic CsPbX₃ (X = I, Br) perovskites without organic component are promising for long-term stability but face main challenges of facile fabrication and phase stability. Here we discover a general organic methylamine acetate salt mediated growth method to deposit high quality phase pure and stable CsPbX₃ (X = I, Br) perovskite films via a novel precursor consisting of stoichiometric cesium acetate (CsAc), methylamine halide (MAX) and lead halide (PbX₂). Interestingly, these organic salts of CsAc and MAX could efficiently promote the crystallization process especially lower the crystallization temperature, but do not introduce the incorporation of organic MA cation into all-inorganic CsPbX₃ perovskites. These phase pure and stable CsPbX₃ perovskites with tunable band gaps can be fabricated into high efficiency photovoltaics. Our organic salt mediated growth of all-inorganic perovskite not only reveals the all-inorganic CsPbX₃ perovskite's unique crystal growth mechanism but also demonstrates their promising application for photovoltaics.

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1. Introduction

The organic-inorganic hybrid perovskites-based photovoltaics with certified 23.3% efficiency record have attracted tremendous research efforts in the past years [1–9]. The hybrid perovskites' chemical instability related to potential release of volatile organic components is one of the most serious challenges for the long-term stabilities [10–13]. Therefore, the all-inorganic perovskites without volatile component become a promising alternative for perovskite solar cells. Among them, the all-inorganic CsPbX₃ (X = I, Br) perovskites are the most practical and promising candidates with significant efficiency progress in the past years [14–17]. Unlike the convenient fabrication of hybrid perovskite via solution chemistry, it is much more difficult to fabricate all-inorganic CsPbX₃ due to its high phase transformation temperature for the black phase [15,18,19]. Recently, several methods, including long-chain ammonium surfactant capping [20,21], CsPbX₃ quantum dots (QDs) [22,23] and acidic assisted method [15], had been reported to reduce the crystallization temperature. Since the organic surfactant used in surfactant capping method and QDs could limit their optoelectronic performance, the most popular and simple method for low temperature fabrication of CsPbX₃

perovskites is using the HX (X = I, Br) acid as additive or using the acidic precursor such as HPbI₃ or PbI₂·xHI [15,24–27]. However, both the high annealing temperature and the corrosive acidic condition would limit their applications when flexible substrate or some acidic sensitive layers are used. It would be urgent to further understanding the fundamental properties especially crystal growth of all-inorganic CsPbX₃ perovskite.

In the previously reported manipulation of organic-inorganic hybrid perovskite crystallization, organic cation component or organic cation halide additives such as methylammonium chloride (MAcI) etc. had been widely used in the deposition of high quality organic-inorganic hybrid perovskites [8,28,29]. However, to the best of our knowledge, no such organic components especially the organic cations had been reported to control the deposition of all-inorganic CsPbX₃ perovskites. The main concern might be the worry of forming organic-inorganic hybrid perovskite because the organic cation like formamidinium (FA⁺) has been demonstrated to form a stable FA-Cs mixed cation perovskite film. In the previous organic cation hybrid perovskite, the different organic cation would also induce cation exchange in the crystallization process [24,29]. In this report, we present a general organic salt containing organic methylammonium (MA⁺) cation and acetate (Ac⁻) ion to cultivate the crystallization of high quality and phase pure CsPbX₃ (X = I, Br) perovskite films without any organic cation alloying under mild low temperature. We found that a novel

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precursor consisting the organic component cesium acetate (CsAc) and methylammonium halide (MAX) as alternative source for CsI with inorganic lead halide salt can realize a facile one-step deposition of high quality CsPbX₃ (X = I, Br) perovskite within seconds after the very fast removal of all-organic by-product of methylammonium acetate (MAAc).

2. Materials and methods

2.1. Materials

PbI₂ (99.9985%), PbBr₂ (99.9985%) and CsAc (99.9%) were obtained from Alfa Aesar Co., Ltd. MAI (99.99%), MABr (99.99%) and Spiro-MeOTAD (99.9%) were bought from Borun New Material Technology Co., Ltd. All the other materials were purchased from Sigma-Aldrich and used as received without any purification. The CsPbI₃ precursor solution was prepared by firstly dissolving 1 mmol PbI₂ and 1 mmol MAI in 2 mL dimethyl sulfoxide (DMSO) and then 1 mmol CsAc powder was added to the solution to form a 0.5 mol/L precursor solution. The precursor solution for CsPbI₂Br and CsPbBr₃ were prepared following the similar procedure but the DMSO solvent was changed to *N*-methyl-2-pyrrolidone (NMP) and DMSO mixture (1:9, v:v) (for CsPbBr₃).

2.2. Device fabrication

A ~20 nm thick compact TiO₂ layer was first coated on the pre-patterned fluorine-doped tin oxide (FTO, AGC, TEC7) by spray pyrolysis of 0.2 mol/L Ti(IV) bis(ethyl acetoacetate)-diisopropoxide 1-butanol solution at 450 °C followed by anneal at 450 °C for 1 h. After the substrates cooled down to room temperature, the substrates were then treated with UV-O₃ for 30 min before the perovskite deposition.

The CsPbX₃ precursor solutions were then spin coated onto the 50 °C pre-warmed c-TiO₂ coated-substrate at 2000 r/min for 30 s following by annealing at 100 °C for 2 min and 1 mg/mL phenyltrimethylammonium iodide (PTAI) solution treatment. A layer of hole transport material (HTM) of 0.1 mol/L spiro-MeOTAD, 0.035 mol/L bis(trifluoromethane) sulfonimide lithium salt (Li-TFSi), and 0.12 mol/L 4-tert-butylpyridine (tBP) in chlorobenzene/acetonitrile (10:1, v:v) solution were then spin coated with at 4000 r/min for 20 s after the films were cooled down to room temperature. Finally, 100-nm-thick Ag contact layer was thermally evaporated as back contact. All the process except for the metal evaporation were processed in a drybox with relative humidity (R.H.) less than 10%.

2.3. Characterization

The absorption spectra of the CsPbX₃ perovskite films were recorded with a Cary-60 UV-vis spectrophotometer. The crystal structures of CsPbX₃ films were taken on a Shimadzu XRD-6100 diffractometer with Cu K α radiation. The morphologies of the CsPbX₃ films were observed by a Bruker MultiMode Nanoscope IIIA atomic force microscope (AFM) and FEI Sirion 200 scanning electron microscope (SEM). The elementary composition of CsPbX₃ films were examined by a spectra were acquired with a Kratos Axis UltraDLD X-ray photoelectron spectroscopy spectrometer (XPS) using a monochromatic Al K source (1486.6 eV). The Nuclear magnetic resonance (NMR) tests were performed on a Bruker AVANCE III 600 MHz NMR Instrument using DMSO *d*₆ as solvent. The photocurrent density-voltage (*J*-*V*) curves of perovskite solar cells was measured by a Keithley 2401 source meter under simulated AM 1.5G illumination (100 mW/cm²; Enlitech SS-F5-3A Class AAA Solar Simulator, the light intensity was calibrated by a stand

Si cell before test) with a scan rate of 0.05 V/s equipped with a non-reflective metal mask with an aperture area of 0.09 cm². The external quantum efficiency (EQE) curves was collected from a QE-3011 system from Enlitech. All the *J*-*V* and EQE test were processed in atmosphere with R.H 30%–45%.

3. Results and discussion

As illustrated in Fig. 1, the novel precursor solutions consisting of stoichiometric CsAc + MAX + PbX₂ were firstly formed by adding the stoichiometric CsAc into a pre-solved MAX + PbX₂ (X = I, Br) solution. Generally, the halide chemical composition of the final CsPbX₃ could be tuned by the PbX₂ + MAX. The CsPbI₃, CsPbI₂Br and CsPbBr₃ perovskite films were prepared from precursor solutions of CsAc + MAI + PbI₂, CsAc + MABr + PbI₂ and CsAc + MABr + PbBr₂, respectively. These CsAc + MAX + PbX₂ precursor solutions can be simply one-step deposited as a smooth precursor film. The precursor films were then conveniently transformed into smooth and compact black perovskite films after a mild temperature annealing process (Fig. S1 online). The annealing temperature (~100 °C) to form black phase CsPbI₃ perovskite is about 200 °C lower than the temperature needed in a conventional method (~300–350 °C).

The UV-vis spectra of annealed CsPbI₃ film in Fig. 2a shows an absorption edge at ~716 nm (~1.73 eV), which is well consistent with previously reported black phase CsPbI₃ perovskite [14,15,20,21,24,25,30–32]. With the alloying of Br, the absorbance edge of the CsPbI₂Br and CsPbBr₃ films blue shifts to ~645 nm (1.92 eV) and ~530 nm (~2.33 eV), respectively. These band gap values are well consistent with the previously reported cubic phase CsPbI₂Br and CsPbBr₃ perovskites [14,30,33–37]. XRD patterns in Fig. 2b also suggest the successful formation of black perovskite phase CsPbX₃ (X = I, Br). As for the CsPbI₃, the characteristic γ phase perovskite peaks at ~14.2°/~14.4° and ~28.6°/~28.9° (Fig. S2 online) indicated the formation of γ -CsPbI₃ rather than the widely reported α -CsPbI₃, which is another black phase CsPbI₃ with slightly distorted crystal structure compared to well-known α -CsPbI₃ [15,18–20,26,42]. The γ -CsPbI₃ perovskite films exhibit much higher XRD peak intensities than the CsPbI₂Br and CsPbBr₃ perovskite films as shown in Fig. S3 (online). For the CsPbI₂Br sample, its (1 0 0) and (2 0 0) peaks shifted to ~14.6° and 29.5° due to the smaller size of Br, revealing the successfully formation of mixed halide CsPbI₂Br perovskite films [30,36–38]. The peak shift became more pronounced for the tri-Br sample of CsPbBr₃, its (1 0 0) and (2 0 0) peaks shift to ~15.3° and 30.8°, which is well consistent with previously reported cubic CsPbBr₃ [33,34,39]. What's more, no impurity peaks related to δ -phase or PbX₂ residue are found in these XRD patterns. All these UV-vis spectra and XRD patterns demonstrate the successful deposition of phase pure CsPbX₃ perovskite films with tunable halide composition by our novel organic component mediated low temperature and non-acidic method.

SEM images in Fig. 2c–e show that all the CsPbI₃, CsPbI₂Br and CsPbBr₃ samples have compact coverage. The XPS analysis was performed on these three different films deposited from precursor solutions of MAI + PbI₂, CsAc + MAI + PbI₂ and CsI + PbI₂ to determine the existence of any organic residuals. Fig. 2f–h reveal that the XPS spectra of CsPbI₃ perovskite film prepared from CsAc + MAI + PbI₂ precursor are almost the same as the CsI + PbI₂ sample without any organic cation components in precursor. Moreover, there is no signal belong to the N 1s found in the XPS spectra of CsPbI₃ sample, while the hybrid MAPbI₃ sample exhibits a strong N 1s peak. These results suggest the absence of MA cation alloying in the sample prepared from CsAc + MAI + PbI₂ precursor. To further exclude the possibility of organic residues including MA

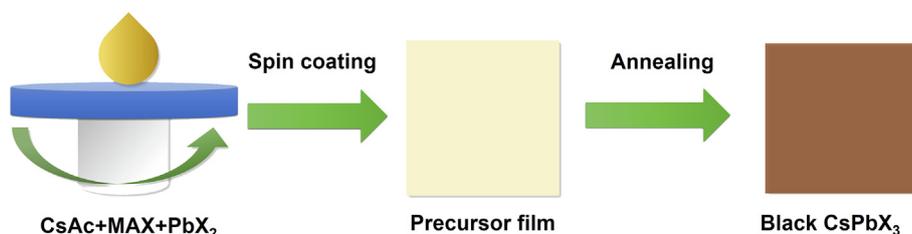


Fig. 1. (Color online) Schematic illustration of growth of black CsPbX₃ (X = I, Br) films using CsAc + MAX + PbX₂ precursor solutions.

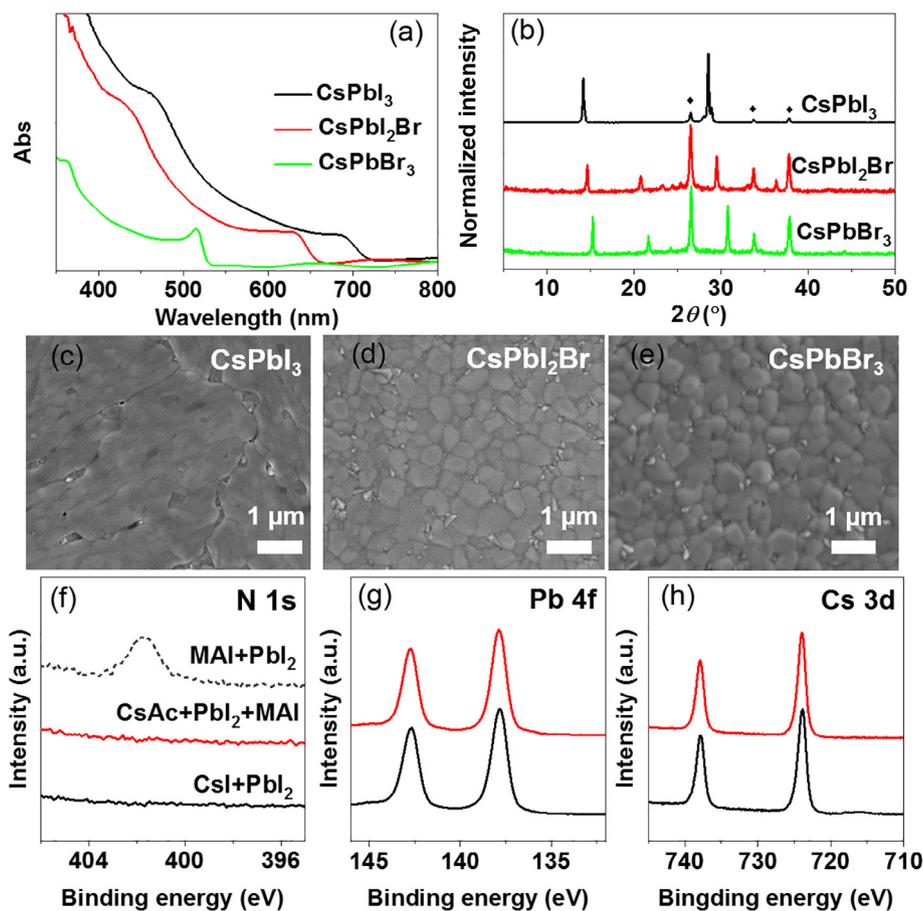
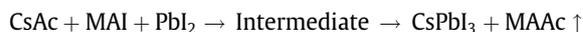


Fig. 2. (Color online) Characterization of the as-fabricated CsPbX₃ perovskite films. (a) UV–vis spectrums, (b) normalized XRD patterns (the raw data is shown in Fig. S3 (online)), (c–e) SEM images of CsPbI₃, CsPbI₂Br and CsPbBr₃ films prepared by CsAc + MAX + PbX₂ precursors. (f) The N 1s core level XPS spectra between MAPbI₃ and CsPbI₃ films prepared by CsI + PbI₂ and CsAc + MAI + PbI₂ precursors. (g, h) Pb 4f and Cs 3d XPS spectra of CsPbI₃ films prepared by CsI + PbI₂ (black) and CsAc + MAI + PbI₂ (red) precursors.

cation and Ac ion, the annealed CsPbI₃ films were dissolved with DMSO *d*₆ for NMR (¹H, ¹³C) measurements. As shown in Fig. S4 (online), there is only the DMSO *d*₆ solvent and H₂O peaks without any detectable residue signal related to MA or Ac [40]. This finding is also well consistent with the facts that all these perovskite samples show characteristic XRD patterns and band gaps of phase pure CsPbX₃ perovskites.

All the above material characterizations show that our novel method can deposit the high quality and phase pure CsPbX₃ perovskites film as convenient as the previous deposition methods for inorganic–organic hybrid perovskites. It is of great significance to explore a fundamental understanding of the crystallization mechanism for the further development of this novel and general method. The CsPbI₃ with the highest black phase transformation temperature was selected as the model for the mechanism study. First of all, we highlight the different crystal growth process between the regular precursor of CsI + PbI₂ without organic component and our novel organic component mediated precursor of

CsAc + MAI + PbI₂. The regular CsI + PbI₂ precursor films only form a pale-yellow film with an absorption peak at ~417 nm after 100 °C annealing (Fig. 3a) and its XRD patterns also show a typical δ-CsPbI₃ peaks at ~10°. Moreover, the SEM images in Fig. S5 (online) reveal lots of pinholes on the perovskite films, indicating the formation of a low quality δ phase CsPbI₃ film. This unsuccessful attempt is quite normal because the black phase transformation temperature of CsPbI₃ is usually up to 350 °C [15,24,37,41,42]. Therefore, we propose that the formation of black phase CsPbI₃ by our novel method should be ascribed to the organic component mediated crystallization procedure. The whole process seems go through the follow steps



The intermediate precursor film consisting organic component of CsAc + MAI and PbI₂ must play an important role in the crystallization process. Based on the previously proposed growth mechanism for mixed FA-MA hybrid perovskites using mixed cation

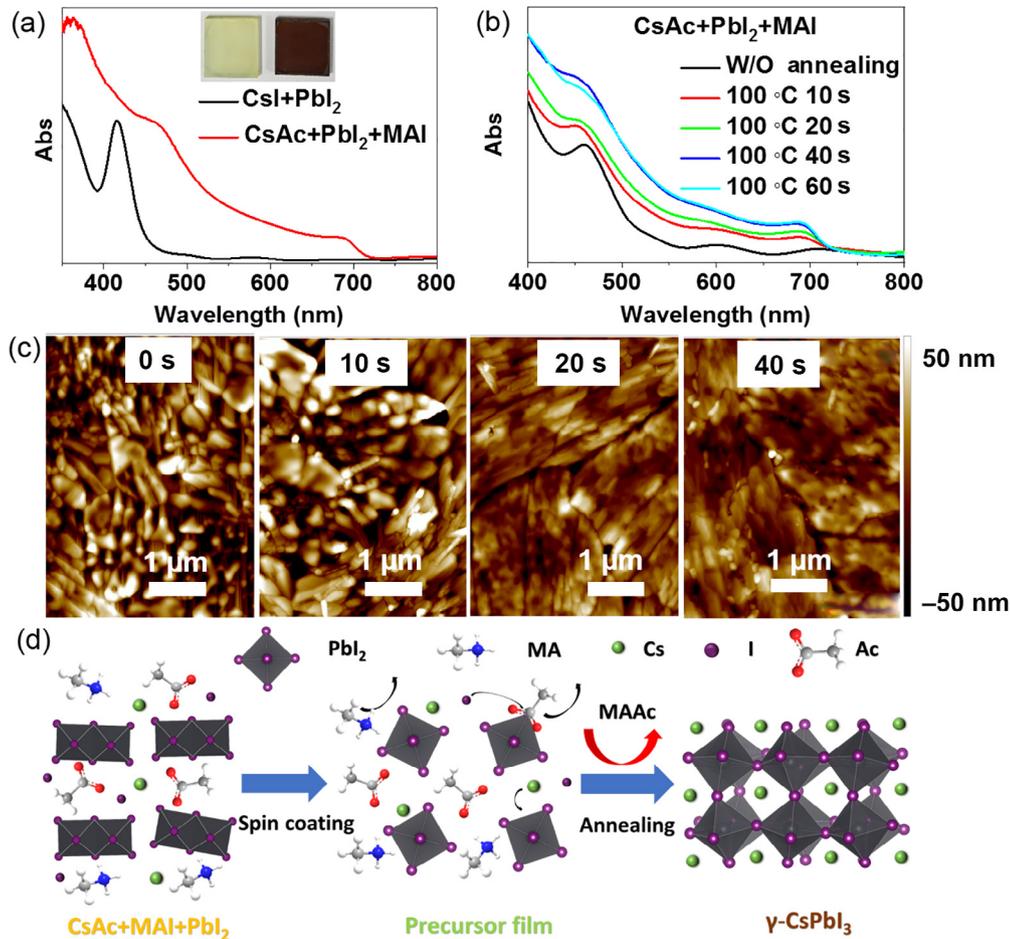


Fig. 3. (Color online) Crystallization mechanism investigation of the growth process. (a) UV-vis spectra of CsPbI₃ films prepared from the CsAc + MAI + PbI₂ and CsI + PbI₂ precursors, respectively. (b) UV-vis spectra evolution and (c) morphologies of CsAc + MAI + PbI₂ precursor films with different annealing duration. (d) Schematic diagram of the proposed crystallization mechanism of CsPbI₃ from CsAc + MAI + PbI₂ precursor.

precursor solutions [29], the MAPbI₃ or MA-Cs mixed perovskite may be formed initially from the CsAc + MAI + PbI₂ precursor, then the Cs⁺ cation from CsAc would be incorporated by replacing the MA cation through a cation exchange reaction to obtain the final phase pure CsPbI₃. However, this MA-Cs cation exchange growth mechanism could be excluded based on the following fact that UV-vis absorbance blue shift related to the cation-exchange process were not observed. In contrast, an absorption edge at ~716 nm immediately appeared during an annealing process as shown in Fig. 3b. There is only absorption intensity increase without any absorbance edge shift during the crystallization process. The freshly deposited CsAc + MAI + PbI₂ precursor film without annealing looks greenish, and its XRD pattern exhibits amorphous feature while the as-spun CsI + PbI₂ film shows typical δ -CsPbI₃ features (Fig. S6 online). The color of the CsAc + MAI + PbI₂ precursor film then immediately changes from greenish to brown after 100 °C annealing for 10 s (Fig. S7 online). Both UV-vis spectra and XRD pattern evolution suggested that the CsPbI₃ perovskite film is highly likely to directly crystallize from precursor film of CsAc + MAI + PbI₂ via annealing. The chemical mechanism behind it might be due to the strong binding energy in all-inorganic perovskite, and previous reports has suggested that the organic cation cannot replace the Cs cation in all-inorganic CsPbX₃ perovskites [32,43].

Based on the above discussion, a solid intermediate precursor film consisting of Cs_xMA_yPbI₃Ac_z composition with some solvent molecular would firstly form after spin coating [44]. In such intermediate precursor film, both the Cs⁺ and MA⁺ cations would

competitively occupy the cation site of Pb-I octahedron [45] and the CH₃COO⁻ (Ac⁻) could coordinate the surface Pb²⁺ site via Pb-CH₃COO⁻ bonds [46,47]. All the two proposed chemical interaction especially the later Pb-CH₃COO⁻ coordination could significantly decrease the symmetry thus greatly reduce the crystallinity of the precursor film. This hypothesis is consistent with both the above-mentioned amorphous feature of the precursor films and the previous mechanism study on deposition of hybrid perovskite using Pb(Ac)₂ precursors [44]. Moreover, this intermediated film seems to be highly unstable, and the organic components could be rapidly removed in the form of highly volatile by-product of MAAC during annealing [46,48,49]. The fast removal of MAAC by-product may lead to the dense nucleation sites, thus benefit the stabilization of initial crystallized CsPbI₃ with small grain size [20,24]. This hypothesized growth mechanism is supported by the morphological evolution of CsPbI₃ perovskite films. As measured by atomic force microscopy (AFM) in Fig. 3c, the as-deposited precursor film and the 10 s annealed precursor film show smaller size morphology while the grain size of 20 and 40 s annealed samples become as large as ~2 μm. The organic component mediated fast nucleation, distortion of Pb-I bonds and low temperature annealing may lead to the formation of γ -CsPbI₃, which is more phase stable at lower temperature than well-known α -CsPbI₃. Based on all abovementioned discussion, we illustrate the proposed crystallization process in Fig. 3d. The stoichiometric CsAc, MAI and PbI₂ dissolved in DMSO would form a Pb-I based complex colloid solution at first; a highly unstable solid intermediate precursor film consisting of Pb-I octahedron, Cs⁺

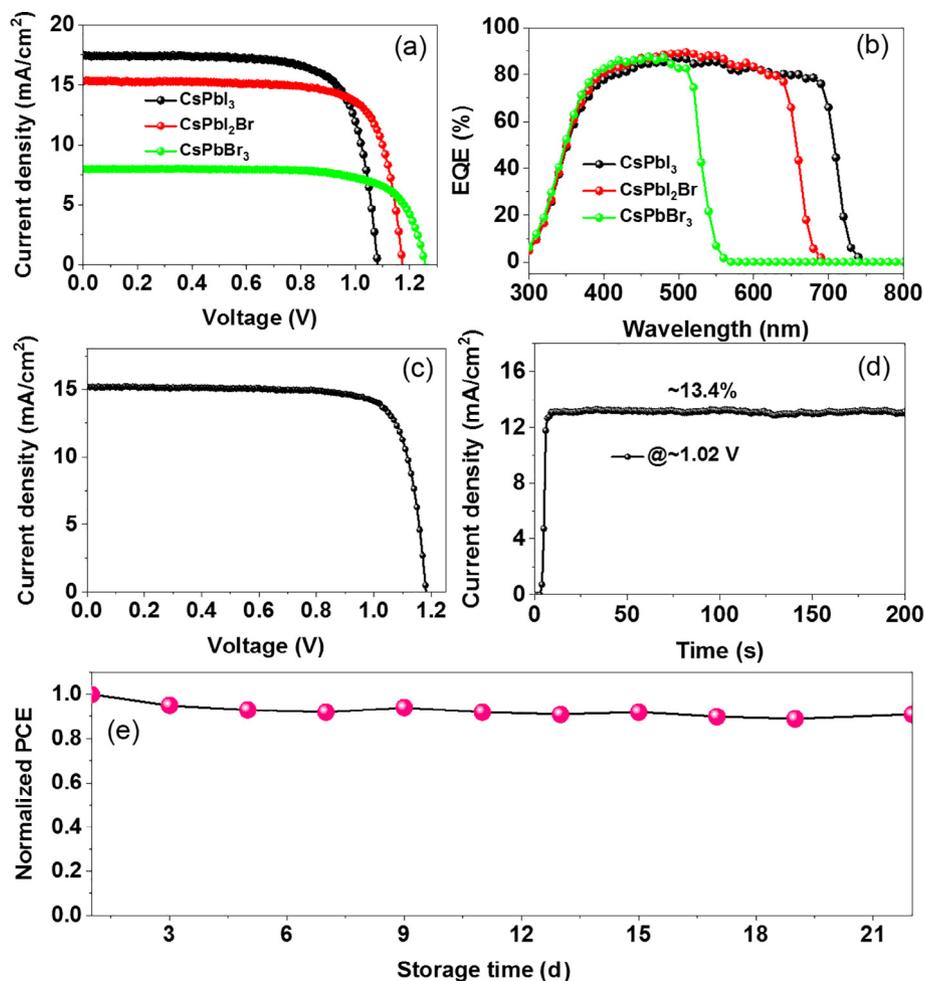


Fig. 4. (Color online) Device performance of the CsPbX₃ based solar cell devices. (a) *J*-*V* curves and (b) EQE curves of typical PTAI passivated CsPbI₃, CsPbI₂Br and CsPbBr₃ solar cells; (c) *J*-*V* curves, (d) stable output and (e) stability test of champion PTAI passivated CsPbI₂Br solar cell (the device was stored in a dark desiccator at room temperature).

and MA⁺ cations and some surface Ac⁻ was then deposited; finally, the thermal annealing induces the crystallization of high quality CsPbI₃ perovskite with the rapid removal of volatile MAAC by-product from the intermediate precursor film.

All the above-mentioned characterizations demonstrated a successful deposition of high quality CsPbX₃ perovskite films by our novel low temperature and non-acidic method. These PTAI passivated stabilized CsPbI₃, CsPbI₂Br and CsPbBr₃ perovskite films were then fabricated into solar cell device with a typical planar structure of FTO/compact-TiO₂/perovskite/Sprio-MeOTAD/Ag. As shown in Fig. 4a and Table S1 (online), the short circuit current (*J*_{sc}) value are ~17.3 mA/cm² (CsPbI₃), ~15.3 mA/cm² (CsPbI₂Br) and ~7.5 mA/cm², respectively. These values are consistent with their EQE curves in Fig. 4d. The open circuit voltage (*V*_{oc}) values increase from 1.08 V (CsPbI₃) to 1.24 V (CsPbBr₃) with the increasing of CsPbX₃ perovskite's band gap. Moreover, a champion CsPbI₂Br based device reach a high efficiency of 14.23% (*J*_{sc} = 15.20 mA/cm², *V*_{oc} = 1.18 V and fill factor (*FF*) = 0.793, under reverse scan) with a stable out of ~13.4% (Fig. 4c and d). Such value is comparable with state-of-the-art efficiency achieved by other high temperature or acidic assisted methods [23,31,35,37,50]. Besides the high efficiency, the champion CsPbI₂Br device also show excellent stability, it could retain more than ~90% initial efficiency after storage in dark desiccator over 3 weeks. The device stability of CsPbI₂Br with larger tolerance factor is much higher than the CsPbI₃ samples because the chemically pure CsPbI₃ is

intrinsically unstable under ambient conditions (Fig. S8 online). The UV-vis absorbance of δ-CsPbI₃ became dominant after exposed to humid air, while the CsPbI₂Br films remain unchanged. Such result is well consisted with previous reports [15,30,38].

4. Conclusions

In summary, we successfully developed a general organic component mediated low temperature solution chemistry method for the deposition of high quality all-inorganic CsPbX₃ (X = I, Br) perovskite films. By using new precursor consisted organic components of CsAc + MAX + PbX₂, high quality CsPbX₃ films could be facilely one-step obtained as convenient as the hybrid perovskites. The low temperature crystallization of all-inorganic perovskite without organic cation alloy should be ascribed to the stronger binding energy in all-inorganic perovskites than hybrid ones. Finally, these PTAI passivated all-inorganic CsPbX₃ perovskites based solar cells exhibited high efficiencies, a CsPbI₂Br based solar cell exhibited stabilized 13.4% output with high stability. Our novel method offers new choice for the low-temperature growth of high quality all-inorganic CsPbX₃ perovskite films for various optoelectronic applications.

Conflict of interest

The authors declare that they have no conflict of interest.

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Author contributions

Yixin Zhao designed and directed the research. Taiyang Zhang, Yong Wang, Xingtao Wang, Min Wu, and Wenhua Liu fabricated and characterized the perovskite thin films and devices. Yixin Zhao and Taiyang Zhang analyzed the results and wrote the manuscript with inputs from all authors.

Appendix A. Supplementary materials

Supplementary materials to this article can be found online at <https://doi.org/10.1016/j.scib.2019.09.022>.

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